

Preliminary Amendment

Applicant: Dr. Haugen Klauk, et al.
Serial No.: *Not yet assigned*
(Priority Application No. DE 10 2004 016 155.0)
(International Application No. PCT/DE2005/000559)
Filed: *Herewith*
(Priority Date: 1 April 2004)
(International Filing Date: 30 March 2005)
Docket No.: I433.251.101/14187
Title: **SENSOR HAVING ORGANIC FIELD EFFECT TRANSISTORS (As Amended)**

IN THE ABSTRACT

Please replace the Abstract with the following rewritten paragraph:

SENSOR HAVING ORGANIC FIELD EFFECT TRANSISTORS (As Amended)

The invention relates to a force sensor based on an organic field effect transistor applied on a substrate ~~is disclosed~~, in which In one embodiment, a mechanical force acting on the transistor causes a change in its source-drain voltage or its source-drain current which corresponds to said force and which can in each case be detected as measurement quantity for the acting force, a diaphragm-based pressure sensor that uses a force sensor of this type, a one- or two-dimensional position sensor that uses a multiplicity of force sensors of this type, and a fingerprint sensor that uses a multiplicity of such force sensors.

(Figure 1)